IP4350CX24

9-channel SD memory card interface ESD protection filter to IEC 61000-4-2 level 4

Rev. 01 — 5 February 2010

Product data sheet

1. Product profile

1.1 General description

The IP4350CX24 is a diode array designed to provide protection to downstream components against ElectroStatic Discharge (ESD) voltages as high as 15 kV.

The IP4350CX24 integrates 9 pairs of rail-to-rail diodes, 12 Zener diodes and 15 resistors in a single wafer-level chip-scale package. It is fabricated using monolithic silicon semiconductor technology and measures only $1.95 \text{ mm} \times 2.11 \text{ mm}$.

These features make the IP4350CX24 ideal for use in applications requiring a high degree of miniaturization, such as mobile phone handsets, cordless telephones and personal digital devices.

1.2 Features

- Pb-free, RoHS compliant and free of halogen and antimony (Dark Green compliant)
- All SD memory card channels with integrated ESD protection, EMI and RF filters
- ESD protection up to 15 kV on 9 channels at output terminals
- Integrated EMI and RF filters with pull-up resistors on 5 channels
- Integrated EMI and RF filters on 4 channels
- Additional SD card power supply protection
- Wafer level chip-scale package with 0.4 mm pitch
- Write protection, card detect biasing resistor integrated
- Supports electrical card detection
- Also available as IP4352CX24 with different filter behavior, same footprint

1.3 Applications

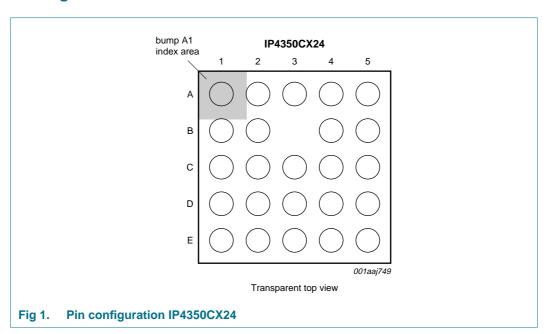
- SD memory card interfaces in cellular and PCS mobile handsets
- Cordless telephones
- Digital still and video cameras
- Media players
- Card readers



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2. Pinning information

2.1 Pinning



2.2 Pin description

Table 1. Pin description

Symbol	Pin	Type[1]	Description
DATA2	A1	I/O	data 2 input or output
DATA3	A2	I/O	data 3 input or output
GND_H	А3	S	supply ground on host side
SDDATA2	A4	I/O	data 2 input or output on SD card side
SDDATA3	A5	I/O	data 3 input or output on SD card side
CD	B1	0	card detect output
CMD	B2	I/O	command input or output on host side
SDCD	B4	I	card detect intput
SDCMD	B5	I/O	command input or output on SD card side
DAT3_PD	C1	I	data 3 pull-down
WP	C2	0	write protect
DAT3_PU	C3	I	data 3 pull-up
SDWP	C4	0	write protect on SD card side
VSD	C5	S	memory card supply voltage
WP+CD	D1	I/O	write protect and card detect
CLK	D2	I/O	clock signal input or output
GND_C	D3	S	card supply ground
SDWP+CD	D4	I/O	write protect and card detect on SD card side
SDCLK	D5	I/O	clock signal on SD card side

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 Table 1.
 Pin description ...continued

Symbol	Pin	Type[1]	Description
DATA1	E1	I/O	data 1 input or output
DATA0	E2	I/O	data 0 input or output
GND_C	E3	S	card supply ground
SDDATA1	E4	I/O	data 1 input or output on SD card side
SDDATA0	E5	I/O	data 0 input or output on SD card side

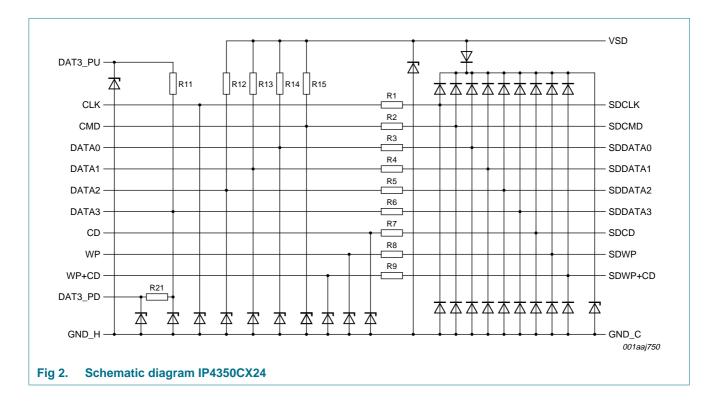
^[1] I = input, O = output, I/O = input and output, S = power supply.

3. Ordering information

Table 2. Ordering information

Type number	Package	ackage					
	Name	Description	Version				
IP4350CX24	WLCSP24	wafer level chip-size package; 24 bumps; $1.95 \times 2.11 \times 0.61$ mm	IP4350CX24/LF				

4. Functional diagram



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5. Limiting values

Table 3. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
V_{I}	input voltage		-0.5	+5.0	V
V _{ESD}	electrostatic discharge voltage	IEC 61000-4-2, level 4; output pins A4, A5, B4, B5, C4, C5, D4, D5, E4, E5 with pins A3, D3, E3 as ground			
		contact discharge	<u>[1]</u> –8	+8	kV
		air discharge	-15	+15	kV
		IEC 61000-4-2, level 1, all other pins with A3, D3, E3 as ground			
		contact discharge	-2	+2	kV
		air discharge	-2	+2	kV
P _{ch}	channel power dissipation	continuous power; T _{amb} = 70 °C	-	25	mW
P _{tot}	total power dissipation	T _{amb} = 70 °C	-	100	mW
T _{stg}	storage temperature		-55	+150	°C
T _{reflow(peak)}	peak reflow temperature	10 s maximum	-	260	°C
T_{amb}	ambient temperature		-30	+85	°C

^[1] Device is qualified with 1000 pulses of ±15 kV contact discharges each, according to the IEC 61000-4-2 model and far exceeds the specified level 4 (8 kV contact discharge).

6. Characteristics

Table 4. Characteristics

 T_{amb} = 25 °C unless otherwise specified.

Parameter	Conditions	Min	Тур	Max	Unit
channel series resistance	R1 to R9	12	15	18	Ω
	R11 to R14	35	50	65	kΩ
	R15	3.29	4.7	6.11	kΩ
	R21	329	47	611	kΩ
channel capacitance	including diode capacitance; $V_I = 0 V$; $f = 1 MHz$	<u>[1]</u>			
	each data channel from SD card to I/O interface	-	8.8	-	pF
	CLK channel	-	7.8	-	pF
	DAT3_PD	-	6	-	pF
	DAT3_PU	-	5	-	pF
	VSD	-	37	-	pF
breakdown voltage	I _I = 1 mA	6	-	-	V
reverse leakage current	V _I = 3 V	-	-	100	nA
	channel series resistance channel capacitance breakdown voltage	$ \begin{array}{c} \text{channel series resistance} & \begin{array}{c} \text{R1 to R9} \\ \text{R11 to R14} \\ \\ \text{R15} \\ \\ \text{R21} \end{array} \\ \\ \text{channel capacitance} & \begin{array}{c} \text{including diode capacitance;} \\ V_{\text{I}} = 0 \text{ V; f} = 1 \text{ MHz} \\ \\ \text{each data channel from SD card} \\ \text{to I/O interface} \\ \\ \text{CLK channel} \\ \\ \text{DAT3_PD} \\ \\ \text{DAT3_PU} \\ \\ \text{VSD} \\ \\ \\ \text{breakdown voltage} & \begin{array}{c} \text{I}_{\text{I}} = 1 \text{ mA} \end{array} $	Channel series resistance R1 to R9 12 R11 to R14 35 R15 3.29 R21 329 Channel capacitance volume Including diode capacitance; VI = 0 V; f = 1 MHz 11 each data channel from SD card to I/O interface - CLK channel - DAT3_PD - DAT3_PU - VSD - breakdown voltage I _I = 1 mA 6	channel series resistance R1 to R9 12 15 R11 to R14 35 50 R15 3.29 4.7 R21 329 47 channel capacitance Including diode capacitance II V _I = 0 V; f = 1 MHz - 8.8 each data channel from SD card to I/O interface - 7.8 DAT3_PD - 6 DAT3_PU - 5 VSD - 37 breakdown voltage I _I = 1 mA 6 -	Channel series resistance R1 to R9 12 15 18 R11 to R14 35 50 65 R15 3.29 4.7 6.11 R21 329 47 611 Channel capacitance Including diode capacitance; VI = 0 V; f = 1 MHz Image: Colspan="4">Image: Colspan="4">I

^[1] Guaranteed by design.

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7. Frequency response

Table 5. Frequency response

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
α_{il} insertion loss	insertion loss	all channels; R _{source} = 50 Ω ; R _L = 50 Ω				
	f < 400 MHz	-	-	3	dB	
		400 MHz < f < 800 MHz	3	-	6	dB
		800 MHz < f < 2.5 GHz	6	-	15	dB
		2.5 GHz < f < 6.0 GHz	15	-	25	dB

Table 6. Time domain response[1]

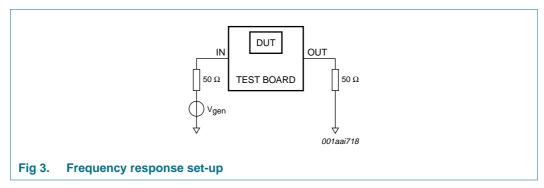
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
high spee	d R _{source} = 50 Ω ; $t_r = t_f = 2 \text{ ns}$	1				
t _r	t _r rise time	load 20 pF 100 kΩ	-	2.3	-	ns
		load 40 pF 100 kΩ	-	3.4	-	ns
t _f	t _f fall time	load 20 pF 100 kΩ	-	2.4	-	ns
		load 40 pF 100 kΩ	-	3.5	-	ns

^[1] All rise or fall times measured using source with 0 V to 3 V steps, 10 % to 90 %.

8. Application information

8.1 Insertion loss

The insertion loss measurement configuration of a typical NetWork Analyzer (NWA) system is shown in <u>Figure 3</u>. The insertion loss is measured with a test PCB utilizing laser drilled micro-via holes that connect the PCB ground plane to the IP4350CX24 ground pins.

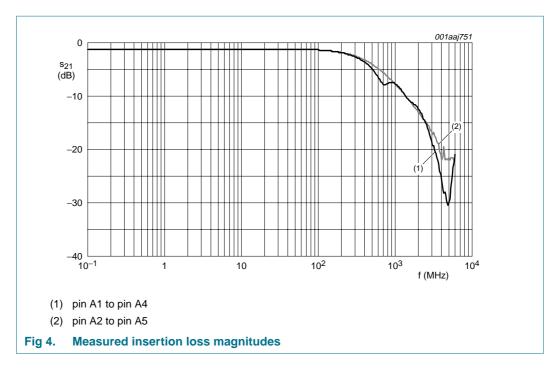


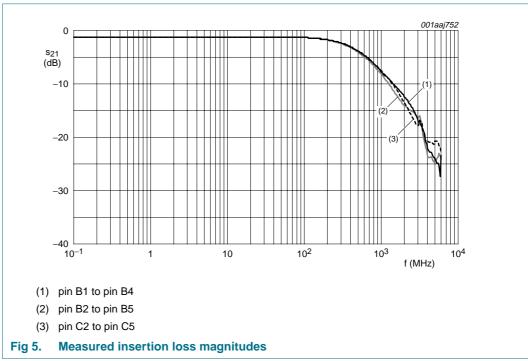
The frequency response curves for all channels at frequencies up to 6 GHz are shown in Figure 4 to Figure 7.

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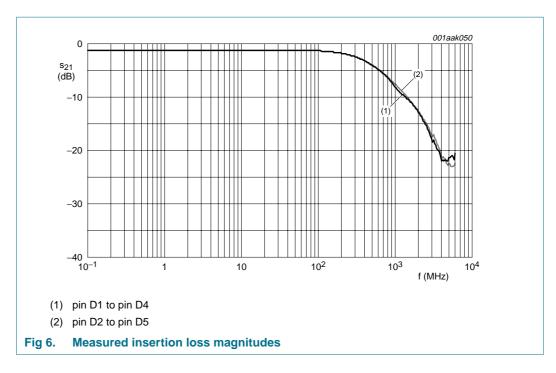
^[2] Performed on all high speed lines (channels including R1 to R9, see Figure 2).

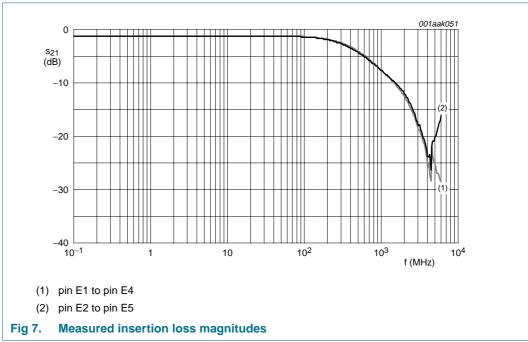
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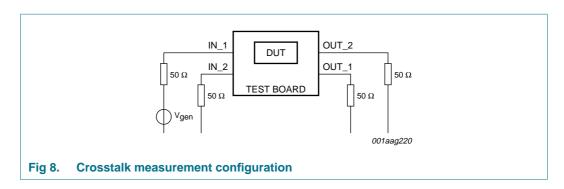


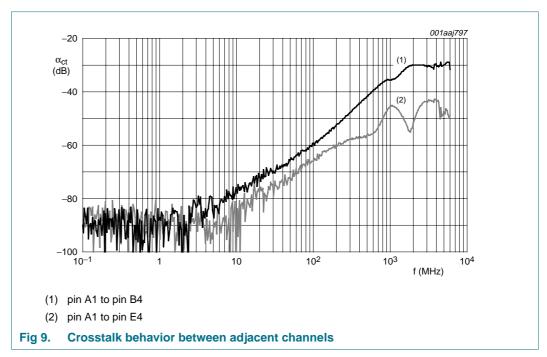


8.2 Crosstalk

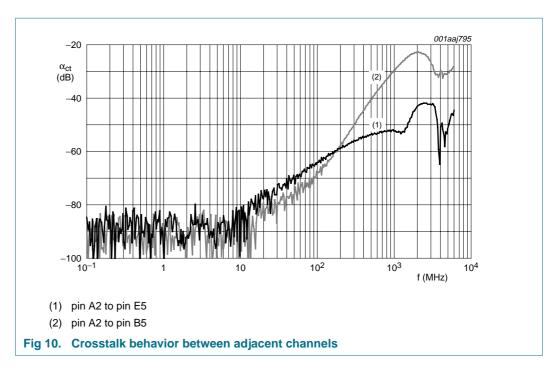
The set-up for crosstalk measurements in a 50 Ω NWA system from one channel to another is shown in <u>Figure 8</u>. Typical examples of crosstalk measurement results are depicted in <u>Figure 9</u>, <u>Figure 10</u> and <u>Figure 11</u>. Unused channels are terminated with 50 Ω to ground.

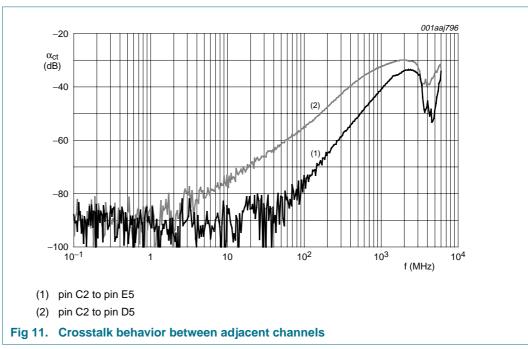
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9. Package outline

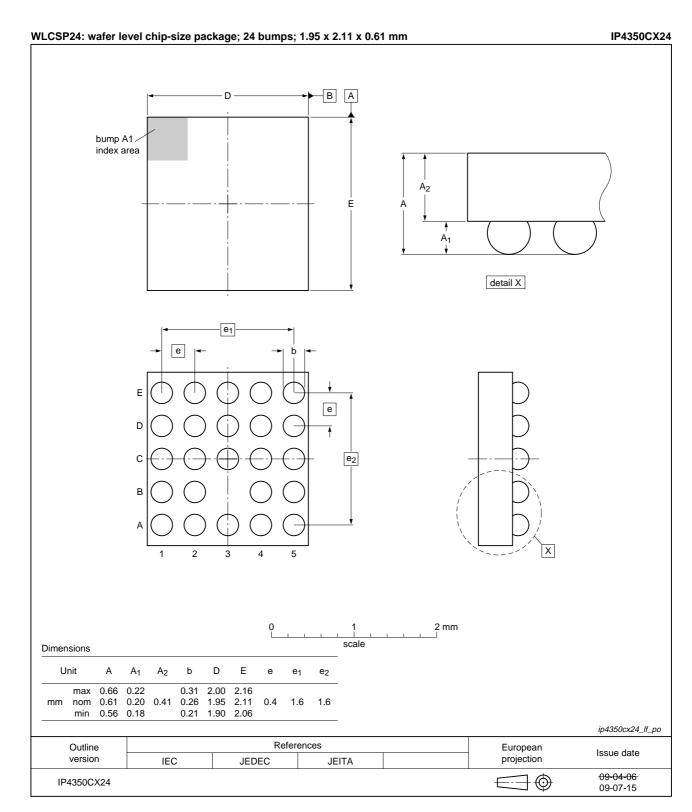


Fig 12. Package outline IP4350CX24/LF (WLCSP24)

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10. Soldering of WLCSP packages

10.1 Introduction to soldering WLCSP packages

This text provides a very brief insight into a complex technology. A more in-depth account of soldering WLCSP (Wafer Level Chip-Size Packages) can be found in application note AN10439 "Wafer Level Chip Scale Package" and in application note AN10365 "Surface mount reflow soldering description".

Wave soldering is not suitable for this package.

All NXP WLCSP packages are lead-free.

10.2 Board mounting

Board mounting of a WLCSP requires several steps:

- 1. Solder paste printing on the PCB
- 2. Component placement with a pick and place machine
- 3. The reflow soldering itself

10.3 Reflow soldering

Key characteristics in reflow soldering are:

- Lead-free versus SnPb soldering; note that a lead-free reflow process usually leads to higher minimum peak temperatures (see <u>Figure 13</u>) than a PbSn process, thus reducing the process window
- Solder paste printing issues, such as smearing, release, and adjusting the process window for a mix of large and small components on one board
- Reflow temperature profile; this profile includes preheat, reflow (in which the board is heated to the peak temperature), and cooling down. It is imperative that the peak temperature is high enough for the solder to make reliable solder joints (a solder paste characteristic) while being low enough that the packages and/or boards are not damaged. The peak temperature of the package depends on package thickness and volume and is classified in accordance with Table 7.

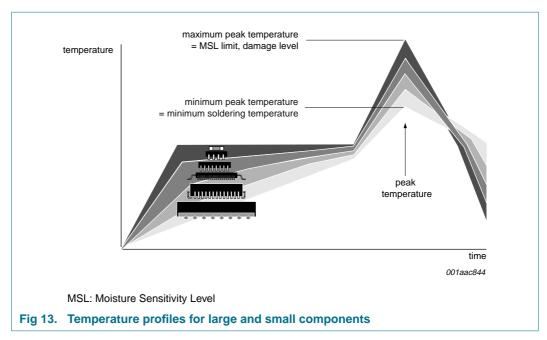
Table 7. Lead-free process (from J-STD-020C)

Package thickness (mm)	Package reflow temperature (°C)				
	Volume (mm³)				
	< 350	350 to 2000	> 2000		
< 1.6	260	260	260		
1.6 to 2.5	260	250	245		
> 2.5	250	245	245		

Moisture sensitivity precautions, as indicated on the packing, must be respected at all times.

Studies have shown that small packages reach higher temperatures during reflow soldering, see Figure 13.

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For further information on temperature profiles, refer to application note *AN10365* "Surface mount reflow soldering description".

10.3.1 Stand off

The stand off between the substrate and the chip is determined by:

- The amount of printed solder on the substrate
- The size of the solder land on the substrate
- The bump height on the chip

The higher the stand off, the better the stresses are released due to TEC (Thermal Expansion Coefficient) differences between substrate and chip.

10.3.2 Quality of solder joint

A flip-chip joint is considered to be a good joint when the entire solder land has been wetted by the solder from the bump. The surface of the joint should be smooth and the shape symmetrical. The soldered joints on a chip should be uniform. Voids in the bumps after reflow can occur during the reflow process in bumps with high ratio of bump diameter to bump height, i.e. low bumps with large diameter. No failures have been found to be related to these voids. Solder joint inspection after reflow can be done with X-ray to monitor defects such as bridging, open circuits and voids.

10.3.3 Rework

In general, rework is not recommended. By rework we mean the process of removing the chip from the substrate and replacing it with a new chip. If a chip is removed from the substrate, most solder balls of the chip will be damaged. In that case it is recommended not to re-use the chip again.

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Device removal can be done when the substrate is heated until it is certain that all solder joints are molten. The chip can then be carefully removed from the substrate without damaging the tracks and solder lands on the substrate. Removing the device must be done using plastic tweezers, because metal tweezers can damage the silicon. The surface of the substrate should be carefully cleaned and all solder and flux residues and/or underfill removed. When a new chip is placed on the substrate, use the flux process instead of solder on the solder lands. Apply flux on the bumps at the chip side as well as on the solder pads on the substrate. Place and align the new chip while viewing with a microscope. To reflow the solder, use the solder profile shown in application note AN10365 "Surface mount reflow soldering description".

10.3.4 Cleaning

Cleaning can be done after reflow soldering.

11. Abbreviations

Table 8. Abbreviations

Acronym	Description
DUT	Device Under Test
EMI	ElectroMagnetic Interference
ESD	ElectroStatic Discharge
NWA	NetWork Analyzer
PCB	Printed-Circuit Board
PCS	Personal Communication System
RFI	Radio Frequency Interference
RoHS	Restriction of Hazardous Substances
SD	Secure Digital

12. Revision history

Table 9. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
IP4350CX24_1	20100205	Product data sheet	-	-

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13. Legal information

13.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
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